

## SEMICONDUCTOR TECHNICAL DATA

## KMB6D0NS30QA

N-Ch MOSFET+SBD

## GENERAL DESCRIPTION

This trench MOSFET has better characteristics, such as fast switching time, low on resistance, low gate charge and excellent avalanche characteristics. The MOSFET and Schottky diode are isolated inside the package. It is mainly suitable for portable equipment and SMPS.

## **FEATURES**

